

Features

Low Power Consumption

- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- Output Short-Circuit Protection
- Low Total Harmonic Distortion...0.003% Typ
- High Input Impedance...JFET-Input Stage
- Latch-Up-Free Operation
- High Slew Rate...13V/µs Typ
- Common-Mode Input Voltage Range Includes V_{cc}+
- SOP-8L: Available in "Green" Molding Compound (No Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

General Description

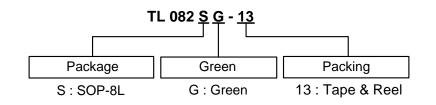
The JFET-input operational amplifier family is designed to offer a wider selection than any previously developed operational amplifier family. Each of these JFET-input operational amplifiers incorporates well-matched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit. The devices feature high slew rates, low input bias and offset currents, and low offset-voltage temperature coefficient.

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Applications

- Active filters
- Audio pre-amps
- Sample and holds
- Peak detectors

Ordering Information



	Device	Package	Packaging (Note 2)	13" Tape and Reel		
	Device	Code		Quantity	Part Number Suffix	
PD,	TL082SG-13	S	SOP-8L	2500/Tape & Reel	-13	

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at

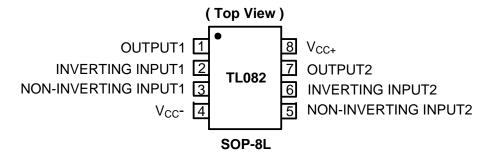
http://www.diodes.com/products/lead_free.html

 Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Pin Assignments

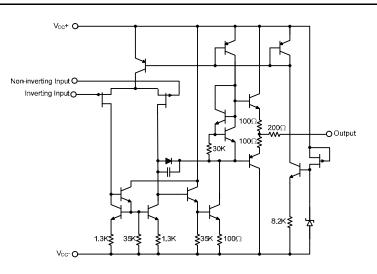
(1) Dual channel SOP-8L



Pin Descriptions

Pin Name	Pin No.	Description
OUTPUT1	1	Channel 1 Output
INVERTING INPUT1	2	Channel 1 Inverting Input
NON-INVERTING INPUT1	3	Channel 1 Non-inverting Input
V _{cc} -	4	Supply Voltage
NON-INVERTING INPUT2	5	Channel 2 Non-inverting Input
INVERTING INPUT2	6	Channel 2 Inverting Input
OUTPUT2	7	Channel 2 Ouput
V _{CC} +	8	Supply Voltage

Block Diagram



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Absolute Maximum Ratings (Note 8)

Symbol	Parameter	Rating	Unit
V _{cc} +	Supply Voltage + (Note 3)	+18	V
V _{cc} -	Supply Voltage - (Note 3)	-18	V
VI	Input voltage (Notes 3 and 5)	±15	V
V _{ID}	Differential input Voltage, V _{ID} (Note 4)	±30	V
	Duration of output short circuit (Note 6)	Unlimited	
P _D	Power Dissipation (Note 7)	860	mW
TJ	Operating Junction Temperature Range	150	°C
T _{ST}	Storage Temperature Range	-65 to +150	°C

Notes: 3. ALL voltage values, except differential voltages, are with respect to the midpoint between V_{CC}+ and V_{CC}-.

4. Differential voltage are at the non-inverting input terminal with respect to the inverting input terminal.

5. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15V, whichever is less.

6. The output may be shorted to ground or either supply. Temperature and/or supply voltage must be limited to ensure that the dissipation rating is not exceeded.

7. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D=(T_J(max)-T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability

Recommended Operating Conditions (Note 8)

Symbol	Description	Rating	Unit
V _{CC} ±	Supply Voltage	±15	V
T _A	Operating Ambient Temperature Range	-40 to +85	°C

Notes: 8. Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended Operating Conditions indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.



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Electrical Characteristics ($V_{CC\pm} = \pm 15V$, $T_A = 25$ °C; unless otherwise noted)

Symbol	Parameter	Test Conditions		Min	Тур.	Max	Unit
V	Input Offset Voltage	V ₀ =0,	T _A =25 °C		3	6	mV
V _{IO}		R _S =50Ω	T _A = full range			9	IIIV
^α v _{IO}	Temperature Coefficient of Input Offset Voltage	$V_0=0$, $R_S=50\Omega$, $T_A=$ full range			18		µV/°C
I _{IO}	Input Offset Current	V ₀ =0	T _A =25 °C		5	100	pА
-10		.0.0	$T_A = $ full range			10	nA
I _{IB}	Input Bias Current	V _o =0	T _A =25 °C		30	200	pА
	Common Mode	T_A = full range				20	nA
V _{ICR}	Input Voltage Range			±11	-12~+15		V
	Maximum Peak Output Voltage Swing	$R_L=10k\Omega$, $T_A=25$ °C		±12	±13.5		
V _{OM}		$R_L \ge 10 k\Omega$,	-T _A = full range	±12			V
		$R_L \ge 2k\Omega$		±10	±12		
Δ	Large Signal Differential	V _O =±10V,	T _A =25 °C	50	200		V/mV
A _{VD} B ₁	Voltage Amplification	$R_L \ge 2k\Omega$	T _A = full range	25			
B ₁	Unity Gain Bandwidth				3		MHz
r _i	Input Resistance	T _A =25 °C			10 ¹²		Ω
CMRR	Common Mode Rejection Ratio	$V_{IC}=V_{ICRmin}, V_{O}=0$ R _S =50Ω, T _A =25 °C		75	86		dB
k _{svr}	Supply Voltage Rejection Ratio (ΔV _{cc} ±/ΔV _{l0})	$V_{cc}=\pm 9 \text{ to } \pm 15V$ $V_{o}=0$ $R_{s}=50\Omega, T_{A}=25 ^{\circ}C$		80	86		dB
I _{cc}	Supply Current (each amplifier)	V _o =0, T _A =25 °C No load			1.4	2.8	mA
V ₀₁ /V ₀₂	Crosstalk Attenuation	A _{VD} =100, T _A =25 °C			120		dB
SR	Slew Rate at Unity Gain	$V_I=10V, C_L=100pF, R_L=2k\Omega$	T _A =25 °C	8	13		V/µs
ÖN		(See Figure 1)	T _A = full range	5			τ, μο
tr	Rise Time	V _I =20mV, R _L =2kΩ, 0	C _L =100pF		0.05		μs
	Overshoot Factor	(See Figure 1)	•		20		%
Ma	Equivalent Input Noise	$R_{s}=20\Omega \qquad \frac{f=1kHz}{f=10 Hz \text{ to } 10kHz}$			18		nV/\sqrt{HZ}
Vn	Voltage				4		μV
In	Equivalent Input Noise Current	$R_s=20\Omega$, f=1kHz			0.01		pA/√HZ
THD	Total Harmonic Distortion				0.003		%
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOP-8L (Note 9)			145		°C/W
θ_{JC}	Thermal Resistance Junction-to-Case	SOP-8L (Note 9)			35		°C/W

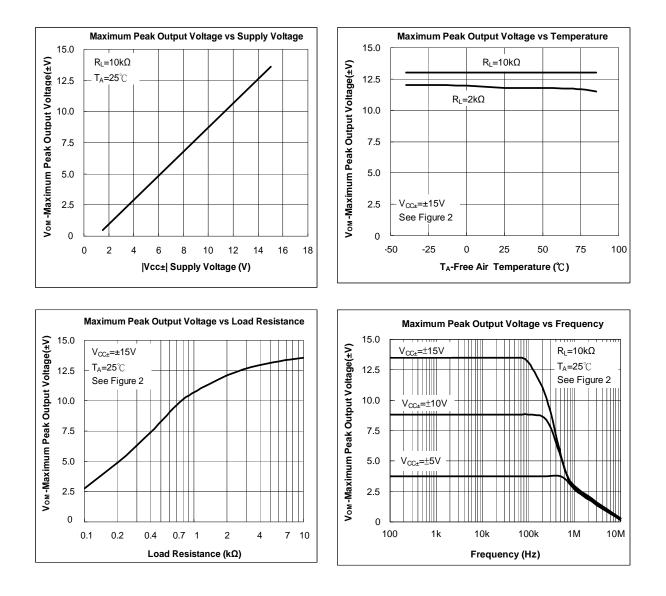
Notes: 9. Test condition for SOP-8L: Devices mounted on FR-4 substrate PC board, with minimum recommended pad layout.

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Typical Performance Characteristics





V_{CC±}=±10V

 $V_{CC\pm}=\pm 5V$

1k

V_{CC±}=±15V

15.0

12.5

10.0

7.5

5.0

2.5

0 L

Voм-Maximum Peak Output Voltage(±V)

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Typical Performance Characteristics (Continued)

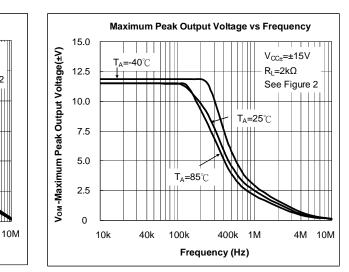
 $R_L=2k\Omega$

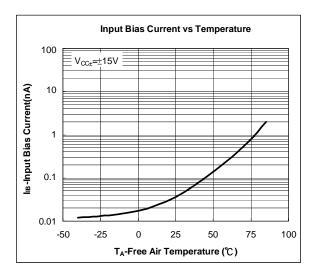
T_A=25℃

1M

See Figure 2

Maximum Peak Output Voltage vs Frequency

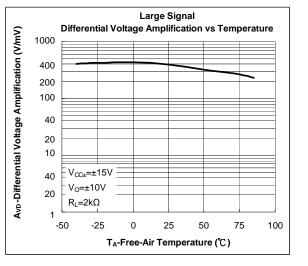




10k

Frequency (Hz)

100k

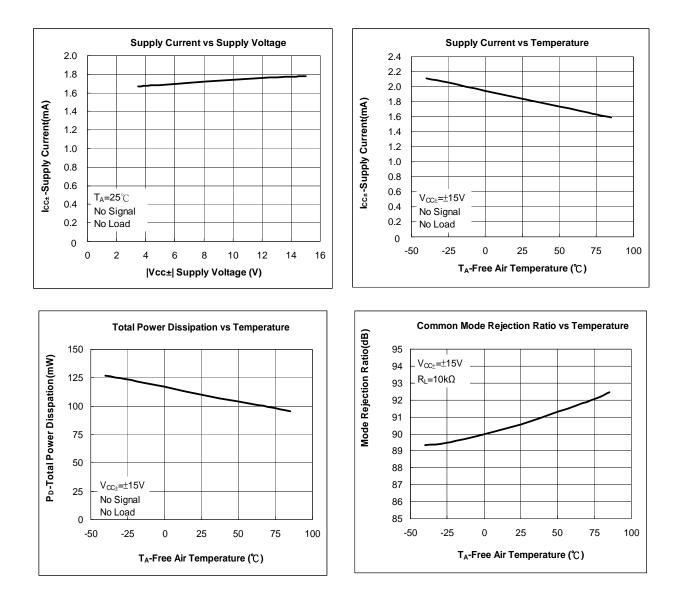


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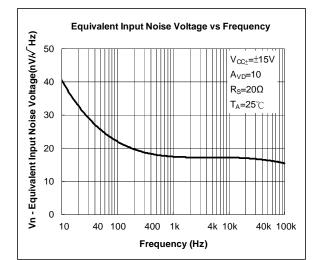
Typical Performance Characteristics (Continued)

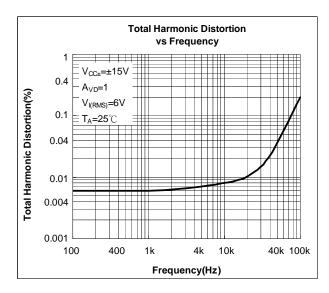


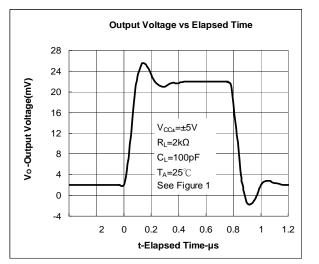
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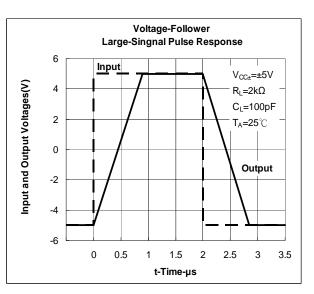
Typical Performance Characteristics (Continued)







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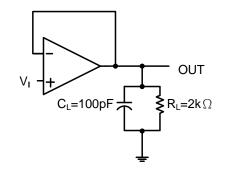




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Test Circuit



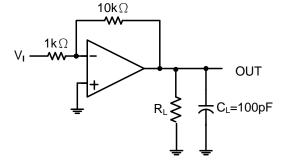
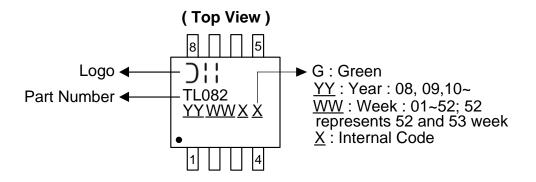


Figure 1. Unity-Gain Amplifier

Figure 2. Gain-of-10 Inverting Amplifier

Marking Information

(1) SOP-8L



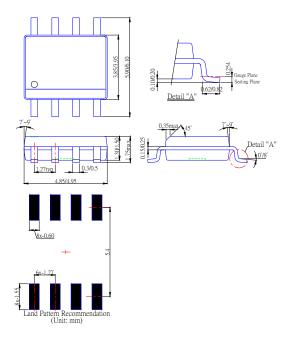


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GENERAL PURPOSE JFET INPUT OPERATIONAL AMPLIFIERS

Package Information (All Dimensions in mm)

(1) Package type: SOP-8L





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